



Switching diode

SOD - 723

• Applications

High speed switching

• Features

- 1) Extremely small surface mounting type.
- 2) High Speed.
- 3) High reliability.

• Construction

Silicon epitaxial planar

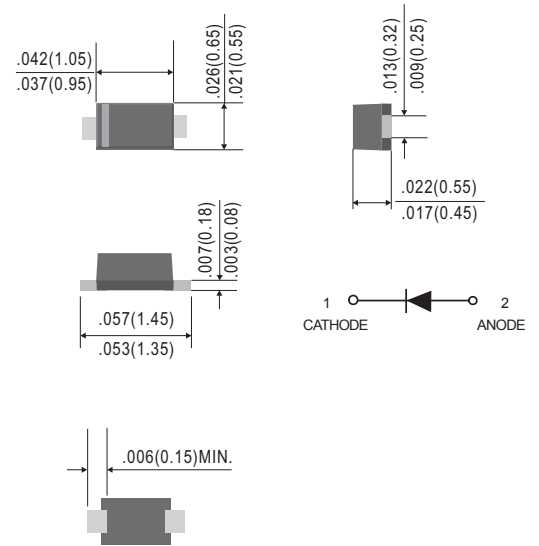
• Device Marking

1SS400G = 3Å 1Å

• Pb-Free package is available

RoHS product for packing code suffix "G"

Halogen free product for packing code suffix "H"



Dimensions in inches and (Millimeters)

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Peak reverse voltage	V_{RM}	90	V
DC reverse voltage	V_R	80	V
Peak forward current	I_{FM}	225	mA
Mean rectifying current	I_O	100	mA
Surge current (1s)	I_{surge}	500	mA
Junction temperature	T_j	125	°C
Storage temperature	T_{stg}	- 55 ~ +125	°C

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_F	-	-	1.2	V	$I_F=100mA$
Reverse current	I_R	-	-	0.1	μA	$V_R=80V$
Capacitance between terminals	C_T	-	0.72	3.0	pF	$V_R=0.5V, f=1MHz$
Reverse recovery time	t_{rr}	-	-	4	ns	$V_R=6V, I_F=10mA, R_L=100\Omega$



ELECTRICAL CHARACTERISTIC CURVES

($T_a = 25^\circ\text{C}$)

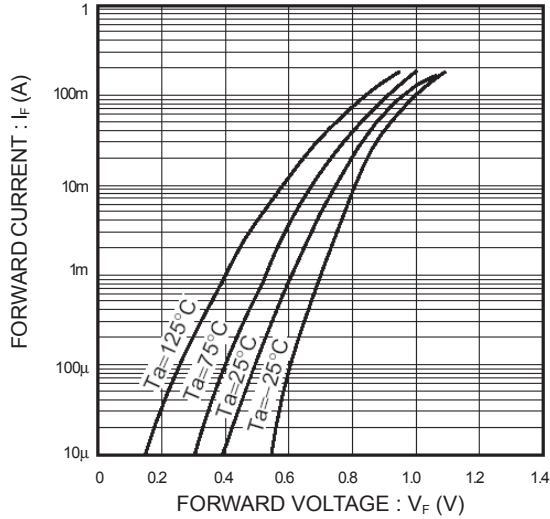


Fig.1 Forward characteristics

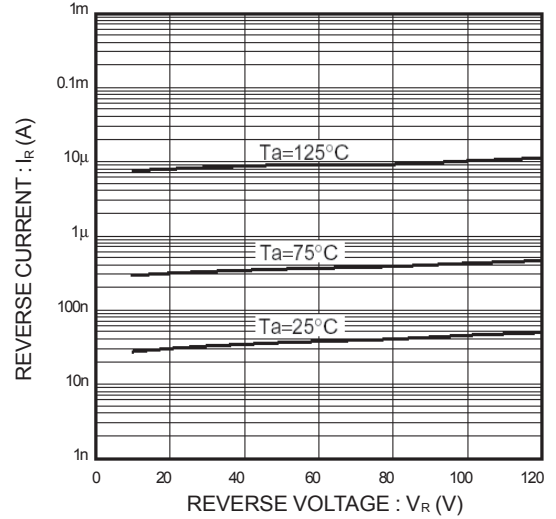


Fig.2 Reverse characteristics

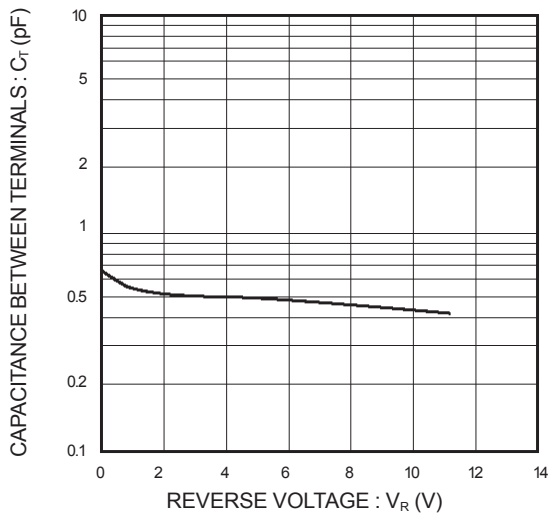


Fig.3 Capacitance between terminals

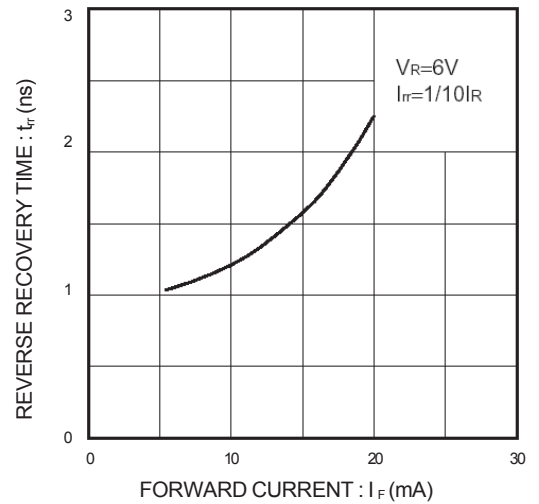


Fig.4 Reverse recovery time characteristics

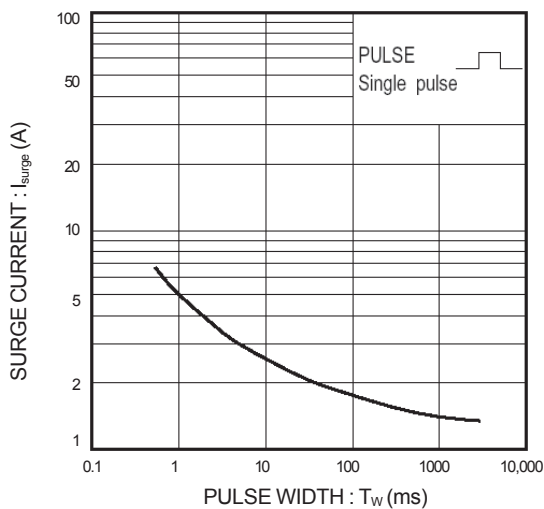


Fig.5 Surge current characteristics

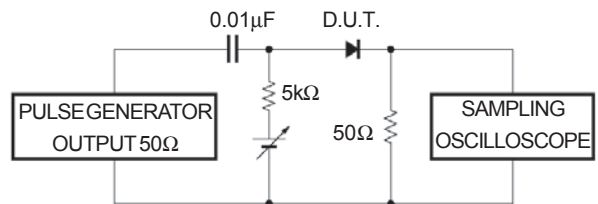


Fig.6 Reverse recovery time (t_{rr}) measurement circuit